

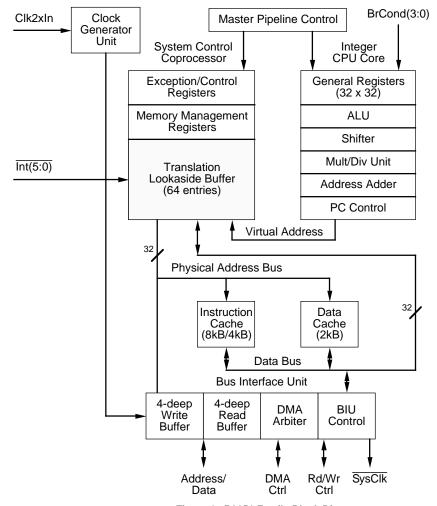
IDT79R3051/79R3052 RISControllers™

IDT79R3051[™], 79R3051E IDT79R3052[™], 79R3052E

FEATURES:

- Instruction set compatible with IDT79R3000A and IDT79R3001 MIPS RISC CPUs
- High level of integration minimizes system cost, power consumption
 - IDT79R3000A /IDT79R3001 RISC Integer CPU
 - R3051 features 4KB of Instruction Cache
 - R3052 features 8KB of Instruction Cache
 - All devices feature 2kB of Data Cache
 - "E" Versions (Extended Architecture) feature full function Memory Management Unit, including 64entry Translation Lookaside Buffer (TLB)
 - 4-deep write buffer eliminates memory write stalls
 - 4-deep read buffer supports burst refill from slow memory devices

- On-chip DMA arbiter
- Bus Interface minimizes design complexity
- Single clock input with 40%-60% duty cycle
- 35 MIPS, over 64,000 Dhrystones at 40MHz
- Low-cost 84-pin PLCC packaging that's pin-/packagecompatible with thermally enhanced 84-pin MQUAD.
- · Flexible bus interface allows simple, low-cost designs
- 20, 25, 33, and 40MHz operation
- · Complete software support
 - Optimizing compilers
 - Real-time operating systems
 - Monitors/debuggers
 - Floating Point Software
 - Page Description Languages



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Figure 1. R3051 Family Block Diagram

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INTRODUCTION

The IDT IDT79R3051 family is a series of high-performance 32-bit microprocessors featuring a high level of integration which are targeted to high-performance, but cost-sensitive embedded processing applications. The IDT79R3051 family is designed to bring the high-performance inherent in the MIPS RISC architecture into low-cost, simplified, power-sensitive applications.

Functional units were integrated onto the CPU core in order to reduce the total system cost, without significantly degrading system performance. Thus, the IDT79R3051 family is able to offer 35MIPS of integer performance at 40MHz without requiring external SRAM or caches.

Furthermore, the IDT79R3051 family brings dramatic power reduction to these embedded applications, allowing the use of low-cost packaging for devices up to 25 MHz. The IDT79R3051 family allows customer applications to bring maximum performance at minimum cost.

Figure 1 shows a block-level representation of the functional units within the IDT79R3051 family. The IDT79R3051 family could be viewed as the embodiment of a discrete solution built around the IDT79R3000A or IDT79R3001. However, by integrating this functionality on a single chip, dramatic cost and power reductions are achieved.

Currently, there are four members of the IDT79R3051 family. All devices are pin- and software-compatible: the differences lie in the amount of instruction cache, and in the memory management capabilities of the processor:

- The IDT79R3052"E" incorporates 8kB of Instruction Cache, and features a full-function Memory Management Unit (MMU), including a 64-entry fully-associative Translation Lookaside Buffer (TLB). This is the same MMU incorporated into the IDT79R3000A and IDT79R3001.
- The IDT79R3052 also incorporates 8kB of Instruction Cache. However, the MMU is a much simpler subset of the capabilities of the enhanced versions of the architecture, and in fact does not use a TLB.
- The IDT79R3051"E"incorporates 4KB of Instruction Cache. Additionally, this device features the same full-function MMU (including TLB file) as the IDT79R3052"E", and IDT79R3000A.
- The IDT79R3051 incorporates 4KB of Instruction Cache, and uses the simpler memory management model of the IDT79R3052.

An overview of the functional blocks incorporated in these devices follows.

CPU Core

The CPU core is a full 32-bit RISC integer execution engine, capable of sustaining close-to single cycle execution rate. The CPU core contains a five stage pipeline and 32 orthogonal 32-bit registers. The IDT79R3051 family implements the MIPS ISA. In fact, the execution engine of the IDT79R3051 family is the same as the execution engine of the IDT79R3000A (and IDT79R3001). Thus the IDT79R3051 family is binary-compatible with those CPU engines.

The execution engine of the IDT79R3051 family uses a five-stage pipeline to achieve close-to single cycle execution. A new instruction can be started in every clock cycle; the execution engine actually processes five instructions concurrently (in various pipeline stages). Figure 2 shows the concurrency achieved by the IDT79R3051 family pipeline.

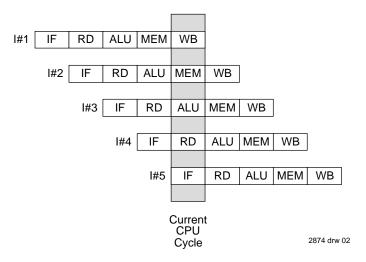


Figure 2. R3051 Family 5-Stage Pipeline

System Control Co-Processor

The R3051 family also integrates on-chip the System Control Co-processor, CP0. CP0 manages both the exception handling capability of the IDT79R3051 family, as well as the virtual to physical mapping of the IDT79R3051 family.

There are two versions of the IDT79R3051 family architecture: the Extended Architecture Versions (the IDT79R3051E and IDT79R3052E) contain a fully associative 64-entry TLB which maps 4KB virtual pages into the physical address space. The virtual to physical mapping thus includes kernel segments which are hard mapped to physical addresses, and kernel and user segments which are mapped on a page basis by the TLB into anywhere within the 4GB physical address space. In this TLB, 8-page translations can be "locked" by the kernel to insure deterministic response in real-time applications. These versions thus use the same MMU structure as that found in the IDT79R3000A and IDT79R3001. Figure 3 shows the virtual-to-physical address mapping found in the Extended Architecture versions of the processor family.

The Extended Architecture devices allow the system designer to implement kernel software to dynamically manage User task utilization of memory resources, and also allow the Kernel to effectively "protect" certain resources from user tasks. These capabilities are important in a number of embedded applications, from process control (where resource protection may be extremely important) to X-Window display systems (where virtual memory management is extremely important), and can also be used to simplify system debugging.

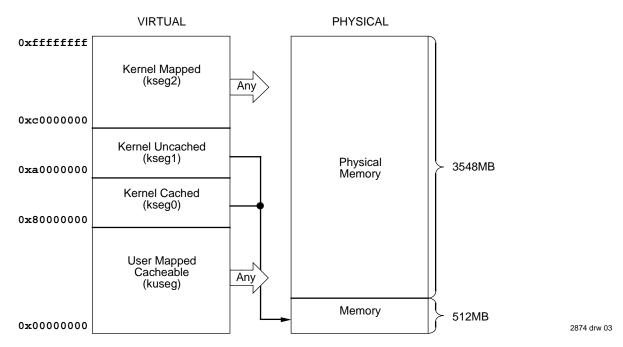


Figure 3. Virtual-to-Physical Mapping of Extended Architecture Versions

The base versions of the architecture (the IDT79R3051 and IDT79R3052) remove the TLB and institute a fixed address mapping for the various segments of the virtual address space. The base processors support distinct kernel and user mode operation without requiring page management software, leading to a simpler software model. The memory mapping used by these devices is illustrated in Figure 4. Note that the reserved address spaces shown are for compatibility with future family members; in the current family members, references to these addresses are translated in the same fashion as their respective segments, with no traps or exceptions taken.

When using the base versions of the architecture, the system designer can implement a distinction between the user tasks and the kernel tasks, without having to execute page management software. This distinction can take the form of physical memory protection, accomplished by address decoding, or in other forms. In systems which do not wish to implement memory protection, and wish to have the kernel and user tasks operate out of a single unified memory space, upper address lines can be ignored by the address decoder, and thus all references will be seen in the lower gigabyte of the physical address space.

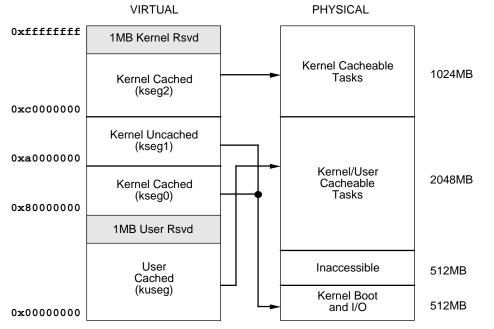


Figure 4. Virtual-to-Physical Mapping of Base Architecture Versions

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Clock Generation Unit

The IDT79R3051 family is driven from a single input clock, capable of operating in a range of 40%-60% duty cycle. On chip, the clock generator unit is responsible for managing the interaction of the CPU core, caches, and bus interface. The clock generator unit replaces the external delay line required in IDT79R3000A and IDT79R3001 based applications.

Instruction Cache

The current family includes two different instruction cache sizes: the IDT79R3051 family (the IDT79R3051 and IDT79R3051E) feature 4KB of instruction cache, and the IDT79R3052 and IDT79R3052E each incorporate 8KB of Instruction Cache. For all four devices, the instruction cache is organized as a line size of 16 bytes (four words). This relatively large cache achieves a hit rate well in excess of 95% in most applications, and substantially contributes to the performance inherent in the IDT79R3051 family. The cache is implemented as a direct mapped cache, and is capable of caching instructions from anywhere within the 4GB physical address space. The cache is implemented using physical addresses (rather than virtual addresses), and thus does not require flushing on context switch.

Data Cache

All four devices incorporate an on-chip data cache of 2KB, organized as a line size of 4 bytes (one word). This relatively large data cache achieves hit rates well in excess of 90% in most applications, and contributes substantially to the performance inherent in the IDT79R3051 family. As with the instruction cache, the data cache is implemented as a direct mapped physical address cache. The cache is capable of mapping any word within the 4GB physical address space.

The data cache is implemented as a write through cache, to insure that main memory is always consistent with the internal cache. In order to minimize processor stalls due to data write operations, the bus interface unit incorporates a 4-deep write buffer which captures address and data at the processor execution rate, allowing it to be retired to main memory at a much slower rate without impacting system performance.

Bus Interface Unit

The IDT79R3051 family uses its large internal caches to provide the majority of the bandwidth requirements of the execution engine, and thus can utilize a simple bus interface connected to slow memory devices.

The IDT79R3051 family bus interface utilizes a 32-bit address and data bus multiplexed onto a single set of pins. The bus interface unit also provides an ALE signal to demultiplex the A/D bus, and simple handshake signals to process processor read and write requests. In addition to the read and write interface, the IDT79R3051 family incorporates a DMA arbiter, to allow an external master to control the external bus.

The IDT79R3051 family incorporates a 4-deep write buffer to decouple the speed of the execution engine from the speed

of the memory system. The write buffers capture and FIFO processor address and data information in store operations, and presents it to the bus interface as write transactions at the rate the memory system can accommodate.

The IDT79R3051/52 read interface performs both single word reads and quad word reads. Single word reads work with a simple handshake, and quad word reads can either utilize the simple handshake (in lower performance, simple systems) or utilize a tighter timing mode when the memory system can burst data at the processor clock rate. Thus, the system designer can choose to utilize page or nibble mode DRAMs (and possibly use interleaving), if desired, in high-performance systems, or use simpler techniques to reduce complexity.

In order to accommodate slower quad-word reads, the IDT79R3051 family incorporates a 4-deep read buffer FIFO, so that the external interface can queue up data within the processor before releasing it to perform a burst fill of the internal caches. Depending on the cost vs. performance tradeoffs appropriate to a given application, the system design engineer could include true burst support from the DRAM to provide for high-performance cache miss processing, or utilize the read buffer to process quad word reads from slower memory systems.

SYSTEM USAGE

The IDT79R3051 family has been specifically designed to easily connect to low-cost memory systems. Typical low-cost memory systems utilize slow EPROMs, DRAMs, and application-specific peripherals. These systems may also typically contain large, slow Static RAMs, although the IDT79R3051 family has been designed to not specifically require the use of external SRAMs.

Figure 5 shows a typical system block diagram. Transparent latches are used to de-multiplex the IDT79R3051/52 address and data busses from the A/D bus. The data paths between the memory system elements and the R3051 family A/D bus is managed by simple octal devices. A small set of simple PALs can be used to control the various data path elements, and to control the handshake between the memory devices and the CPU.

DEVELOPMENT SUPPORT

The IDT79R3051 family is supported by a rich set of development tools, ranging from system simulation tools through prom monitor support, logic analysis tools, and subsystem modules.

Figure 7 is an overview of the system development process typically used when developing IDT79R3051 family-based applications. The IDT79R3051 family is supported by powerful tools through all phases of project development. These tools allow timely, parallel development of hardware and software for IDT79R3051/52 based applications, and include tools such as:

 A program, Cache-3051, which allows the performance of an IDT79R3051 family based system to be modeled and understood without requiring actual hardware.

- · Sable, an instruction set simulator.
- Optimizing compilers from MIPS, the acknowledged leader in optimizing compiler technology.
- IDT Cross development tools, available in a variety of development environments.
- The high-performance IDT floating point library software, which has been integrated into the compiler toolchain to allow software floating point to replace hardware floating point without modifying the original source code.
- The IDT Evaluation Board, which includes RAM, EPROM, I/O, and the IDT Prom Monitor.
- The IDT Laser Printer System board, which directly drives a low-cost print engine, and runs Microsoft TrueImage™ Page Description Language on top of PeerlessPage™ Advanced Printer Controller BIOS.
- Adobe PostScript[™] Page Description Language, ported to the R3000 instruction set, runs on the IDT79R3051 family.
- The IDT Prom Monitor, which implements a full prom monitor (diagnostics, remote debug support, peek/poke, etc.).
- An In-Circuit Emulator, developed and sold by Embedded Performance. Inc.

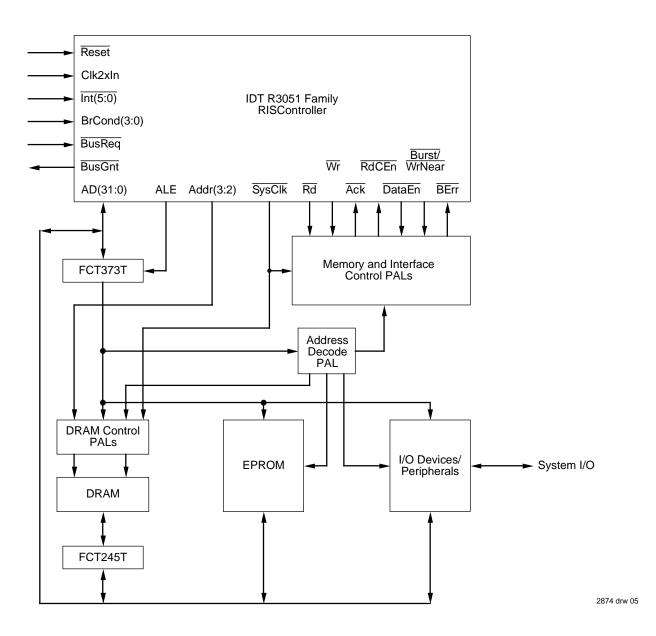


Figure 5. Typical R3051 Family Based System

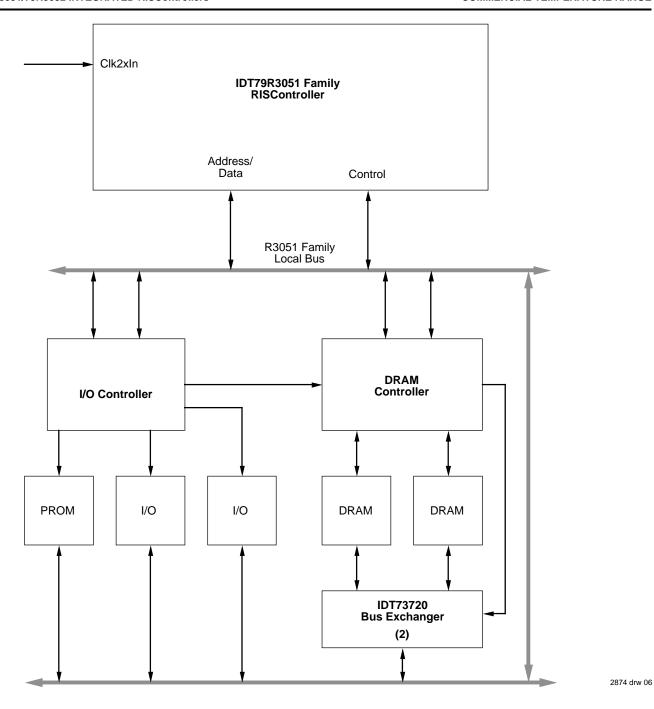


Figure 6. R3051 Family Chip Set Based System

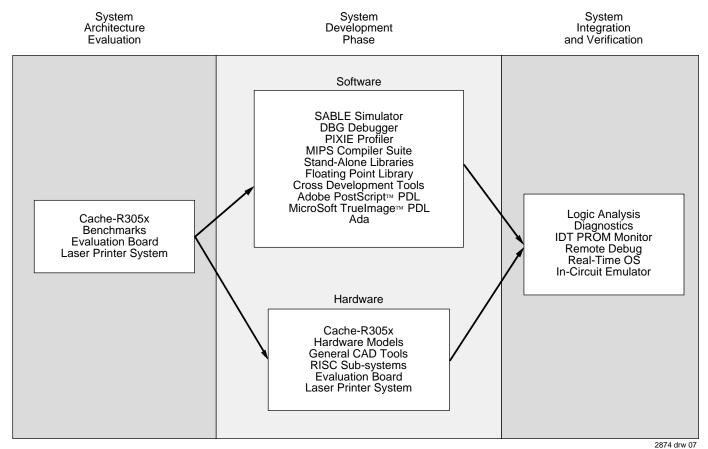


Figure 7. R3051 Family Development Toolchain

PERFORMANCE OVERVIEW

The IDT79R3051 family achieves a very high level of performance. This performance is based on:

- An efficient execution engine. The CPU performs ALU operations and store operations at a single cycle rate, and has an effective load time of 1.3 cycles, and a branch execution rate of 1.5 cycles (based on the ability of the compilers to avoid software interlocks). Thus, the execution engine achieves over 35MIPS performance when operating out of cache.
- Large on-chip caches. The IDT79R3051 family contains caches which are substantially larger than those on the majority of today's embedded microprocessors. These large caches minimize the number of bus transactions required, and allow the R3051 family to achieve actual sustained performance, very close to its peak execution rate.
- Autonomous multiply and divide operations. The IDT79R3051 family features an on-chip integer multiplier/ divide unit which is separate from the other ALU. This allows the IDT79R3051 family to perform multiply or divide operations in parallel with other integer operations, using a single multiply or divide instruction rather than "step" operations.
- Integrated write buffer. The IDT79R3051 family features a
 four-deep write buffer, which captures store target addresses and data at the processor execution rate and retires
 it to main memory at the slower main memory access rate.
 Use of on-chip write buffers eliminates the need for the
 processor to stall when performing store operations.
- Burst read support. The IDT79R3051 family enables the system designer to utilize page mode or nibble mode RAMs when performing read operations to minimize the main memory read penalty and increase the effective cache hit rates.

These techniques combine to allow the processor to achieve 35MIPS integer performance, and over 64,000 dhrystones at 40MHz without the use of external caches or zero wait-state memory devices.

SELECTABLE FEATURES

The IDT79R3051 family allows the system designer to configure some aspects of operation. These aspects are established when the device is reset and include:

- Big Endian vs. Little Endian operation: The part can be configured to operate with either byte ordering convention, and in fact may also be dynamically switched between the two conventions. This facilitates the porting of applications from other processor architectures, and also permits intercommunications between various types of processors and databases.
- Data cache refill of one or four words: The memory system must be capable of performing 4-word transfers to satisfy cache misses. This option allows the system designer to choose between one- and four-word refill on data cache misses, depending on the performance each option brings to his application.

THERMAL CONSIDERATIONS

The IDT79R3051 family utilizes special packaging techniques to improve the thermal properties of high-speed processors. Thus, all versions of the IDT79R3051 family are packaged in cavity-down packaging.

The lowest cost members of the family use a standard cavity-down, injection molded PLCC package (the "J" package). This package, coupled with the power reduction techniques employed in the design of the IDT79R3051 family, allows operation at speeds to 25MHz. However, at higher speeds, additional thermal care must be taken.

For this reason, the IDT79R3051 family is also available in the MQUAD package (the "MJ" package), which is an allaluminum package with the die attached to a normal copper lead-frame, mounted to the aluminum casing. The MQUAD allows for more efficient thermal transfer between the die and the case of the part due to the heat-spreading effect of the aluminum. The aluminum offers less internal resistance from one end of the package to the other, which reduces the temperature gradient across the package, and, therefore, presents a greater area for convection and conduction to the PCB for a given temperature. Even nominal amounts of airflow will dramatically reduce the junction temperature of the die, resulting in cooler operation. The MQUAD package is available at all frequencies, and is pin- and form-compatible with the PLCC package. Thus, designers can choose to utilize this package without changing their PCB.

The members of the IDT79R3051 family are guaranteed in a case temperature range of 0°C to +85°C. The type of package, speed (power) of the device, and airflow conditions affect the equivalent ambient conditions which meet this specification.

The equivalent allowable ambient temperature, Ta, can be calculated using the thermal resistance from case to ambient $(\emptyset CA)$ of the given package. The following equation relates ambient and case temperature:

$$TA = TC - P * ØCA$$

where P is the maximum power consumption at hot temperature, calculated by using the maximum Icc specification for the device.

Typical values for ØCA at various airflows are shown in Table 1 for the various packages.

			Airflo	w (ft/mi	in)	
ØCA	0	200	400	600	800	1000
"J" Package	29	26	21	18	16	15
"MJ" Package*	22	14	12	11	9	8

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Table 1. Thermal Resistance (ØcA) at Various Airflows (*estimated: final values tbd)

PIN DESCRIPTION

PIN NAME	I/O		DESCRIPTION
A/D(31:0)	I/O		ne multiplexed bus which indicates the desired address for a bus transaction sed to transmit data between the CPU and external memory resources during
			s are logically separated into two phases: during the first phase, information ited to the memory system to be captured using the ALE output. This
		Address(31:4):	The high-order address for the transfer is presented on A/D(31:4).
		BE(3:0):	These strobes indicate which bytes of the 32-bit bus will be involved in the transfer, and are represented on A/D(3:0).
		On read cycles, the bus red	s contains the data to be stored and is driven from the internal write buffer. ceives the data from the external resource, in either a single data transaction and places it into the on-chip read buffer.
Addr(3:2)	0	Specifically, this two bit bus	bus which indicates which word is currently expected by the processor. presents either the address bits for the single word to be transferred (writes unctions as a two bit counter starting at '00' for burst read operations.
Diag(1)	0		tput indicates whether the current bus read transaction is due to an on- presents part of the miss address. The value output on this pin is time
		Cached:	During the phase in which the A/D bus presents address information, this pin is an active high output which indicates whether the current read is a result of a cache miss. The value of this pin at this time in other than read cycles is undefined.
		Miss Address (3):	During the remainder of the read operation, this output presents address bit (3) of the address the processor was attempting to reference when the cache miss occurred. Regardless of whether a cache miss is being processed, this pin reports the transfer address during this time.
Diag(0)	0		put distinguishes cache misses due to instruction references from those due sents the remaining bit of the miss address. The value output on this pin is
		I∕Ō:	If the "Cached" Pin indicates a cache miss, then a high on this pin at this time indicates an instruction reference, and a low indicates a data reference. If the read is not due to a cache miss but rather an uncached reference, then this pin is undefined during this phase.
		Miss Address (2):	During the remainder of the read operation, this output presents address bit (2) of the address the processor was attempting to reference when the cache miss occurred. Regardless of whether a cache miss is being processed, this pin reports the transfer address during this time.
ALE	0		sed to indicate that the A/D bus contains valid address information for the bus used by external logic to capture the address for the transfer, typically using
DataEn	0	during read cycles, and thus onto this bus without having	s signal indicates that the A/D bus is no longer being driven by the processor the external memory system may enable the drivers of the memory system g a bus conflict occur. During write cycles, or when no bus transaction is ated, thus disabling the external memory drivers.

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PIN DESCRIPTION (Continued):

PIN NAME	I/O	DESCRIPTION
Burst/ WrNear	0	Burst Transfer/Write Near: On read transactions, the Burst signal indicates that the current bus read is requesting a block of four contiguous words from memory. This signal is asserted only in read cycles due to cache misses; it is asserted for all I-Cache miss read cycles, and for D-Cache miss read cycles if selected at device reset time.
		On write transactions, the WrNear output tells the external memory system that the bus interface unit is performing back-to-back write transactions to an address within the same 256 word page as the prior write transaction. This signal is useful in memory systems which employ page mode or static column DRAMs, and allows near writes to be retired quickly.
Rd	0	Read: An output which indicates that the current bus transaction is a read.
Wr	0	Write: An output which indicates that the current bus transaction is a write.
Ack	1	Acknowledge: An input which indicates to the device that the memory system has sufficiently processed the bus transaction, and that the CPU may either terminate the write cycle or process the read data from this read transfer.
RdCEn	I	Read Buffer Clock Enable: An input which indicates to the device that the memory system has placed valid data on the A/D bus, and that the processor may move the data into the on-chip Read Buffer.
SysClk	0	System Reference Clock: An output from the CPU which reflects the timing of the internal processor "Sys" clock. This clock is used to control state transitions in the read buffer, write buffer, memory controller, and bus interface unit.
BusReq	I	DMA Arbiter Bus Request: An input to the device which requests that the CPU tri-state its bus interface signals so that they may be driven by an external master.
BusGnt	0	DMA Arbiter Bus Grant. An output from the CPU used to acknowledge that a BusReq has been detected, and that the bus is relinquished to the external master.
SBrCond(3:2) BrCond(1:0)	I	Branch Condition Port: These external signals are internally connected to the CPU signals CpCond(3:0). These signals can be used by the branch on co-processor condition instructions as input ports. There are two types of Branch Condition inputs: the SBrCond inputs have special internal logic to synchronize the inputs, and thus may be driven by asynchronous agents. The direct Branch Condition inputs must be driven synchronously.
BErr	I	Bus Error: Input to the bus interface unit to terminate a bus transaction due to an external bus error. This signal is only sampled during read and write operations. If the bus transaction is a read operation, then the CPU will take a bus error exception.
<u>Int</u> (5:3) <u>SInt</u> (2:0)	I	Processor Interrupt: During normal operation, these signals are logically the same as the Int(5:0) signals of the R3000. During processor reset, these signals perform mode initialization of the CPU, but in a different (simpler) fashion than the interrupt signals of the R3000.
		There are two types of interrupt inputs: the SInt inputs are internally synchronized by the processor, and may be driven by an asynchronous external agent. The direct interrupt inputs are not internally synchronized, and thus must be externally synchronized to the CPU. The direct interrupt inputs have one cycle lower latency than the synchronized interrupts.
Clk2xln	I	Master Clock Input: This is a double frequency input used to control the timing of the CPU.
Reset	I	Master Processor Reset: This signal initializes the CPU. Mode selection is performed during the last cycle of Reset.
Rsvd(4:0)	I/O	Reserved: These five signal pins are reserved for testing and for future revisions of this device. Users must not connect these pins.

2874 tbl 03

ABSOLUTE MAXIMUM RATINGS^(1, 3)

Symbol	Rating	Commercial	Unit
VTERM	Terminal Voltage with Respect to GND	-0.5 to +7.0	V
Tc	Operating Case Temperature	0 to +85	°C
TBIAS	Temperature Under Bias	-55 to +125	°C
Тѕтс	Storage Temperature	-55 to +125	°C
VIN	Input Voltage	-0.5 to +7.0	V

NOTES:

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- 1. Stresses greater than those listed under ABSOLUTE MAXIMUM RATINGS may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect reliability.
- 2. VIN minimum = -3.0V for pulse width less than 15ns. VIN should not exceed Vcc +0.5V.
- 3. Not more than one output should be shorted at a time. Duration of the short should not exceed 30 seconds.

AC TEST CONDITIONS

Symbol	Parameter	Min.	Max.	Unit
VIH	Input HIGH Voltage	3.0	_	V
VIL	Input LOW Voltage	_	0	V
VIHS	Input HIGH Voltage	3.5	_	V
VILS	Input LOW Voltage	_	0	V

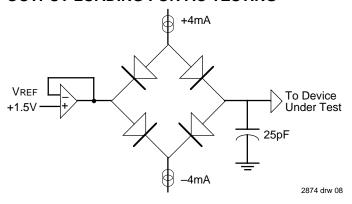
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RECOMMENDED OPERATING TEMPERATURE AND SUPPLY VOLTAGE

Grade	Temperature	GND	Vcc
Commercial	0°C to +85°C	0V	5.0 ±5%
	(Case)		

2874 tbl 06

OUTPUT LOADING FOR AC TESTING



DC ELECTRICAL CHARACTERISTICS (Tc = 0° C to +85°C, Vcc = +5.0V ±5%)

			201	ЛHz	25	MHz	33.33	BMHz	401	ИHz	
Symbol	Parameter	Test Conditions	Min.	Max.	Min.	Max.	Min.	Max.	Min.	Max.	Unit
Vон	Output HIGH Voltage	Vcc = Min., IoH = -4mA	3.5	_	3.5	_	3.5	_	3.5	_	V
Vol	Output LOW Voltage	Vcc = Min., IoL = 4mA	_	0.4	_	0.4	_	0.4	_	0.4	V
VIH	Input HIGH Voltage ⁽³⁾	_	2.0	_	2.0	_	2.0	_	2.0	_	V
VIL	Input LOW Voltage ⁽¹⁾	_	_	0.8	_	0.8	_	0.8	_	0.8	V
VIHS	Input HIGH Voltage ^(2,3)	_	3.0	_	3.0	_	3.0	_	3.0	_	V
VILS	Input LOW Voltage ^(1,2)	_	_	0.4	_	0.4	_	0.4	_	0.4	V
CIN	Input Capacitance ⁽⁴⁾	_	_	10	_	10	_	10	_	10	pF
Соит	Output Capacitance ⁽⁴⁾	_	_	10	_	10	_	10	_	10	pF
Icc	Operating Current	Vcc = 5V, Tc = 25°C	_	350	_	400	_	450	_	500	mA
lін	Input HIGH Leakage	VIH = VCC	_	100	_	100	_	100	_	100	μΑ
lıL	Input LOW Leakage	VIL = GND	-100	_	-100	_	-100	_	-100	_	μΑ
loz	Output Tri-state Leakage	VOH = 2.4V, VOL = 0.5V	-100	100	-100	100	-100	100	-100	100	μΑ
IOTES:			•		•		•		•	2	874 tbl 07

NOTES:

- 1. VIL Min. = -3.0V for pulse width less than 15ns. VIL should not fall below -0.5V for larger periods.
- 2. Vihs and Vils apply to Clk2xIn and Reset.
- 3. Vih should not be held above Vcc + 0.5V.
- 4. Guaranteed by design.

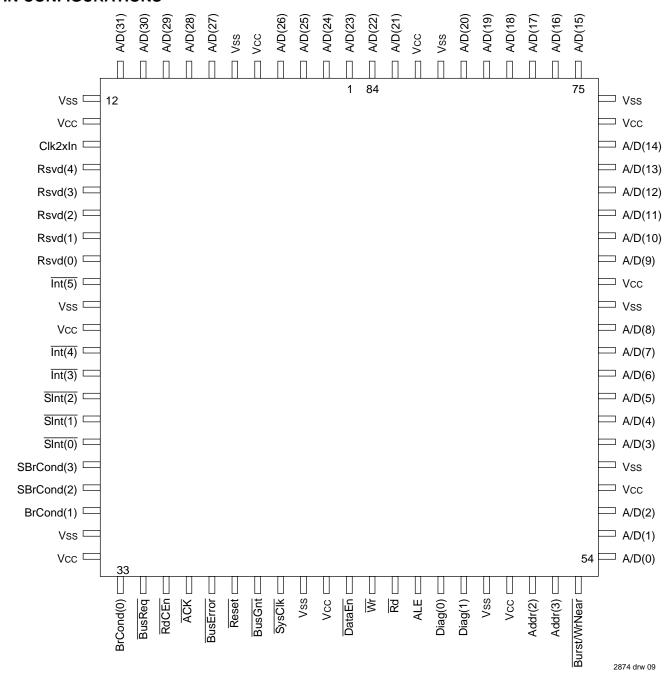
AC ELECTRICAL CHARACTERISTICS (1, 2, 3) (Tc = 0°C to +85°C, Vcc = +5.0V ±5%)

			20	20MHz		25MHz		3MHz	z 40MHz		
Symbol	Signals	Description	Min.	Max.	Min.	Max.	Min.	Max.	Min.	Max.	Unit
t1	BusReq, Ack, BusError, RdCEn,	Set-up to SysClk rising	6	_	5	_	4	_	3	_	ns
t1a	A/D	Set-up to SysClk falling	7	_	6	_	5	_	4.5	_	ns
t2	BusReq, Ack, BusError, RdCEn,	Hold from SysClk rising	4	_	4	_	3	_	3	_	ns
t2a	A/D	Hold from SysClk falling	2	_	2	_	1	_	1	_	
t3	A/D, Addr, Diag, ALE, Wr Burst/WrNear, Rd, DataEn	Tri-state from SysClk rising	_	10	_	10	_	10	_	10	ns
t4	A/D, Addr, Diag, ALE, Wr Burst/WrNear, Rd, DataEn	Driven from SysClk falling	_	10	_	10	_	10	_	10	ns
t5	BusGnt	Asserted from SysClk rising	_	8	_	7	_	6	_	5	ns
t6	BusGnt	Negated from SysClk falling	_	8	_	7	_	6	_	5	ns
t7	Wr, Rd, Burst/WrNear, A/D	Valid from SysClk rising	_	5	_	5	_	4	_	3.5	ns
t8	ALE	Asserted from SysClk rising	_	4	_	4	_	3	_	3	ns
t9	ALE	Negated from SysClk falling	_	4	_	4	_	3	_	3	ns
t10	A/D	Hold from ALE negated	2	_	2	_	1.5	_	1.5	_	ns
t11	DataEn	Asserted from SysClk falling	_	15	_	15	_	13	_	12	ns
t12	DataEn	Asserted from A/D tri-state ⁽⁴⁾	0	_	0	_	0	_	0	_	ns
t14	A/D	Driven from SysClk rising(4)	0	_	0	_	0	_	0	_	ns
t15	Wr, Rd, DataEn, Burst/WrNear	Negated from SysClk falling	_	7	_	6	_	5	_	4	ns
t16	Addr(3:2)	Valid from SysClk	_	6	_	6	_	5	_	4.5	ns
t17	Diag	Valid from SysClk	_	12	_	11	_	10	_	9	ns
t18	A/D	Tri-state from SysClk falling	_	10	_	10	_	9	_	8	ns
t19	A/D	SysClk falling to data out	_	12	_	11	_	10	_	9	ns
t20	Clk2xln	Pulse Width HIGH	10	_	8	_	6.5	_	5.6	_	ns
t21	Clk2xln	Pulse Width LOW	10	_	8	_	6.5	_	5.6	_	ns
t22	Clk2xIn	Clock Period	25	250	20	250	15	250	12.5	250	ns
t23	Reset	Pulse Width from Vcc valid	200	_	200	_	200	_	200	_	μs
t24	Reset	Minimum Pulse Width	32	_	32	_	32	_	32	_	tsys
t25	Reset	Set-up to SysClk falling	6	_	5	_	4	_	3	_	ns
t26	Īnt	Mode set-up to Reset rising	6	_	5	_	4	_	3	_	ns
t27	<u>Int</u>	Mode hold from Reset rising	2.5	_	2.5	_	2.5	_	2.5	_	ns
t28	SInt, SBrCond	Set-up to SysClk falling	6	_	5	_	4	_	3	_	ns
t29	SInt, SBrCond	Hold from SysClk falling	3	_	3	_	2	_	2	_	ns
t30	Int, BrCond	Set-up to SysClk falling	6	_	5	_	4	_	3	_	ns
t31	Int, BrCond	Hold from SysClk falling	3	_	3	_	2	_	2	_	ns
tsys	SysClk	Pulse Width	2*t22								
t32	SysClk	Clock HIGH Time	t22 – 2	t22 + 2	t22 – 2	t22 + 2	t22 – 1	t22 + 1	t22 – 1	t22 + 1	ns
t33	SysClk	Clock LOW Time	t22 – 2	t22 + 2	t22 – 2	t22 + 2	t22 – 1	t22 + 1	t22 – 1	t22 + 1	ns
tderate	All outputs	Timing deration for loading over 25pf ^(4, 5)	_	0.5	_	0.5	_	0.5	_	0.5	ns/ 25pF

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- All timings referenced to 1.5V, with a rise and fall time of less than 2.5ns.
 All outputs tested with 25pF loading.
 The AC values listed here reference timing diagrams contained in the R3051 Family Hardware User's Manual.
- 5. This parameter is used to derate the AC timings according to the loading of the system. This parameter provides a deration for loads over the specified test condition; that is, the deration factor is applied for each 25pF over the specified test load condition.

PIN CONFIGURATIONS



84-Pin PLCC/MQUAD Top View

NOTE:

Reserved Pins must not be connected.

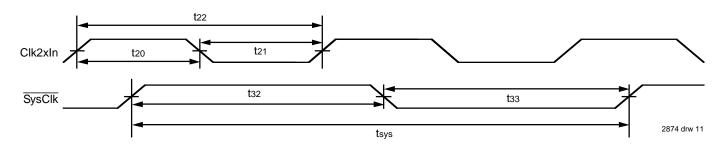


Figure 8. R3051 Family Clocking

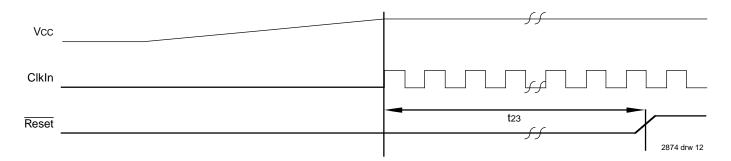


Figure 9. Power-On Reset Sequence

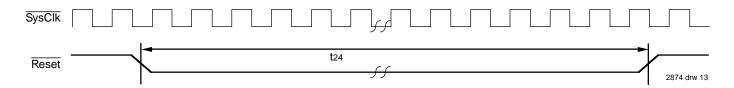


Figure 10. Warm Reset Sequence

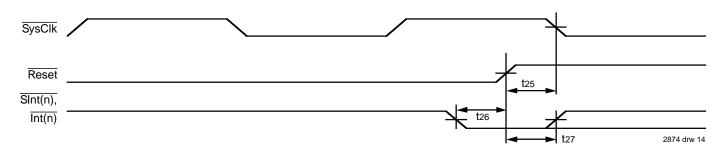


Figure 11. Mode Selection and Negation of Reset

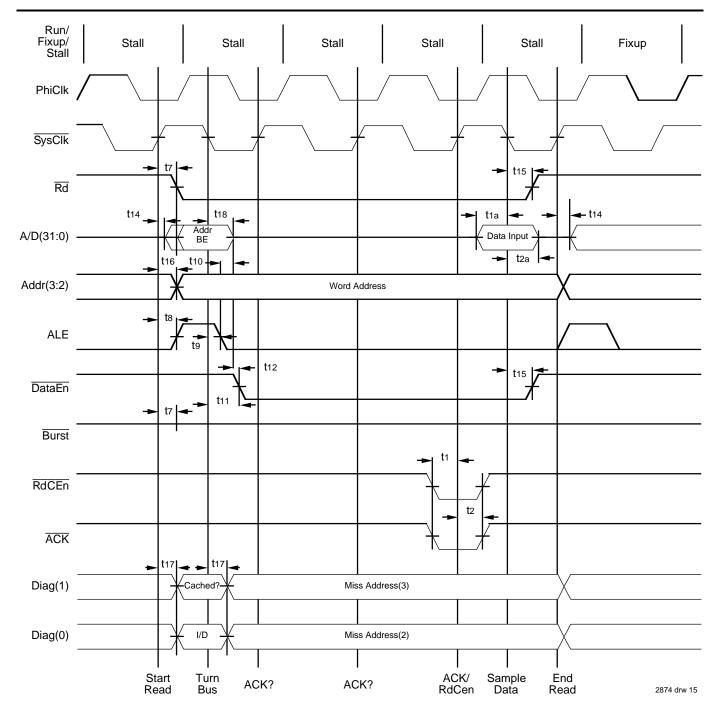


Figure 12. Single Datum Read in R3051 Family

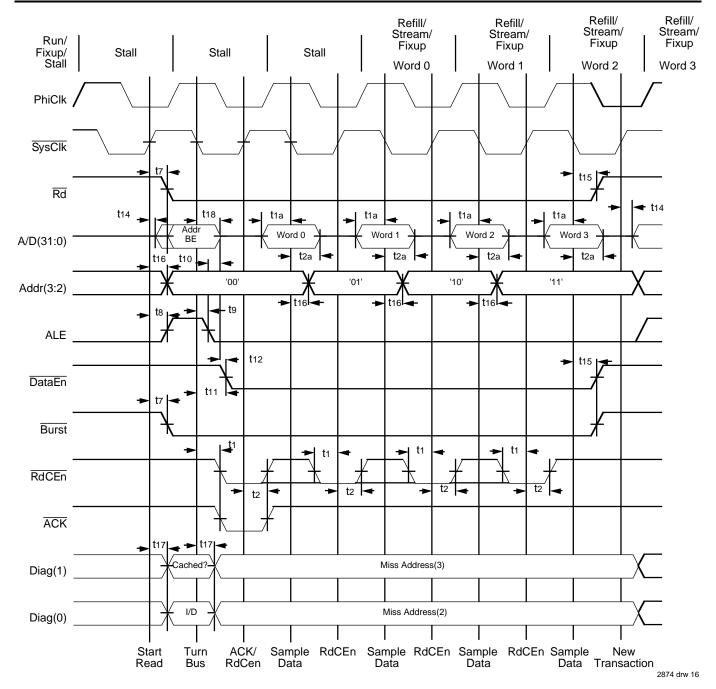


Figure 13. R3051 Family Burst Read

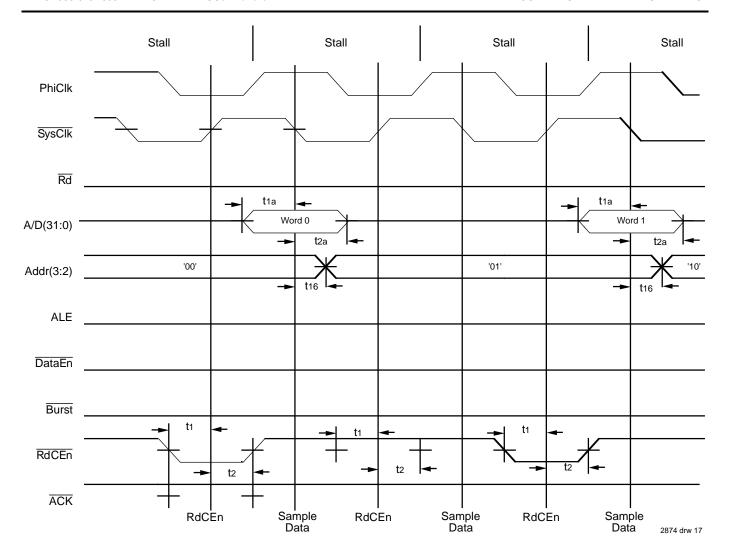


Figure 14 (a). Start of Throttled Quad Read

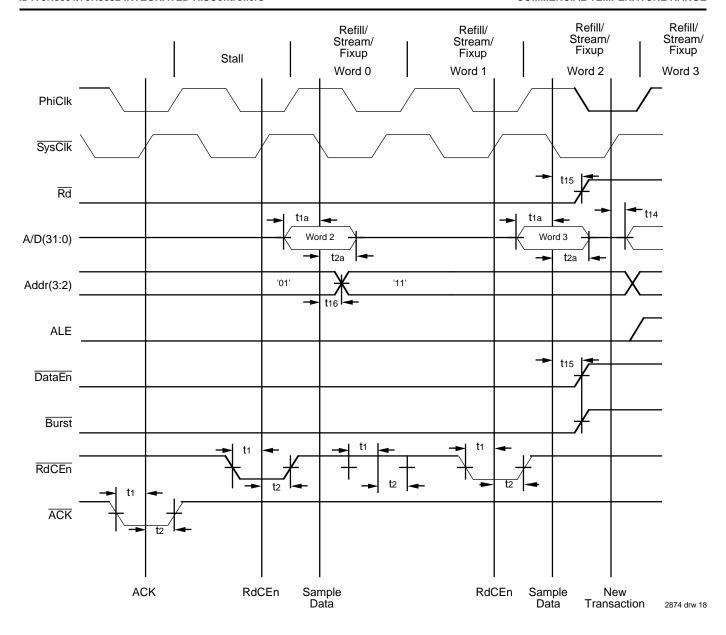


Figure 14 (b). End of Throttled Quad Read

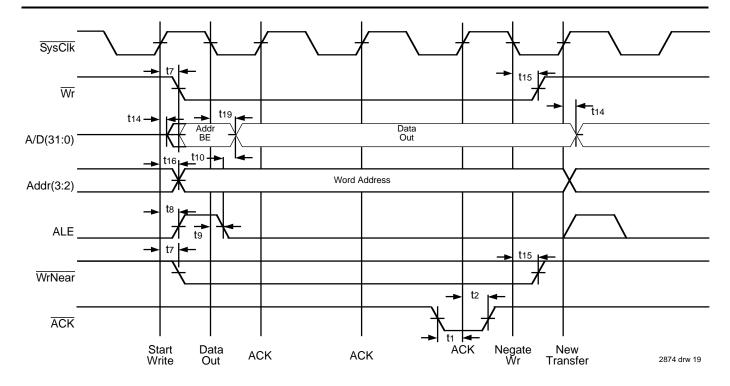


Figure 15. R3051 Family Write Cycle

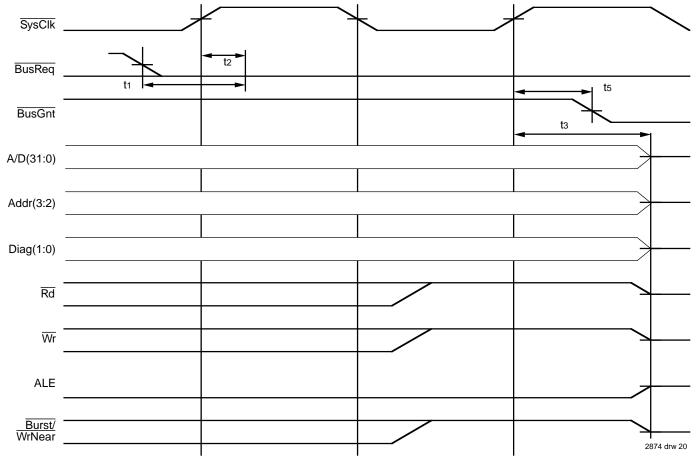


Figure 16. Request and Relinquish of R3051 Family Bus to External Master

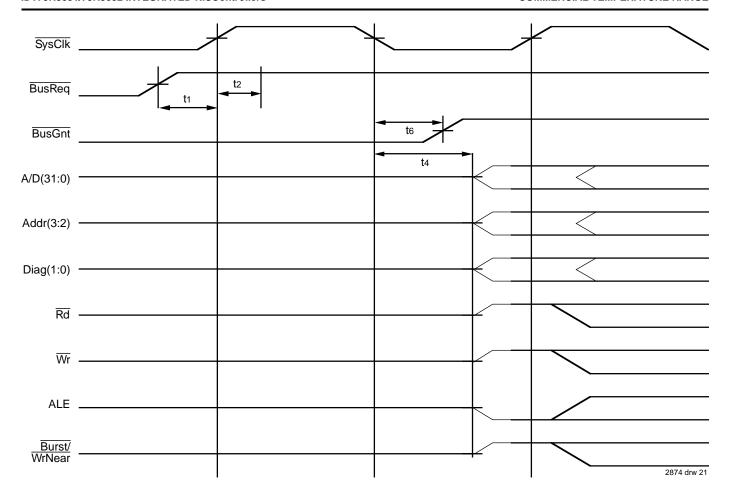


Figure 17. R3051 Family Regaining Bus Mastership

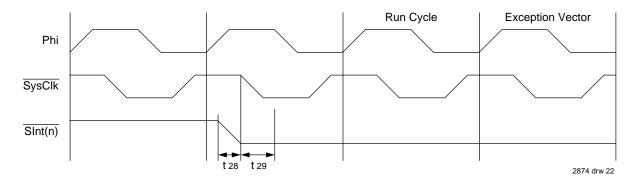


Figure 18. Synchronized Interrupt Input Timing

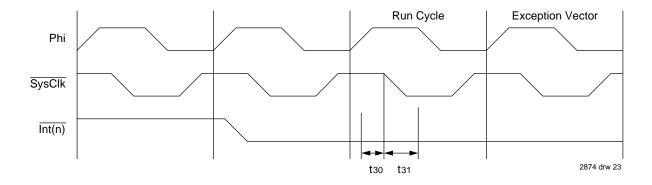


Figure 19. Direct Interrupt Input Timing

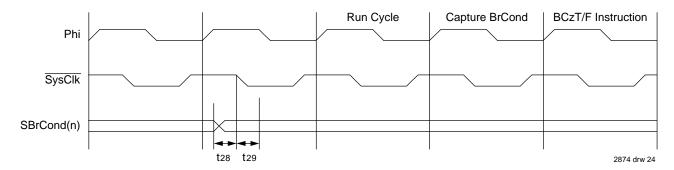


Figure 20. Synchronized Branch Condition Input Timing

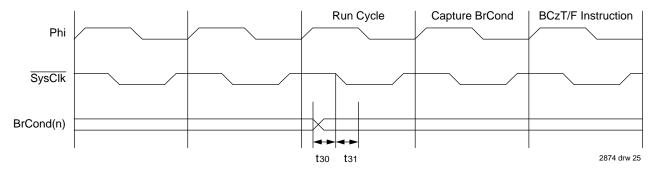
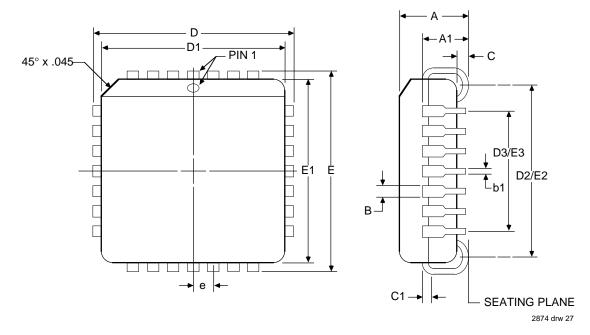


Figure 21. Direct Branch Condition Input Timing

84 LEAD PLCC/MQUAD(7) (SQUARE)

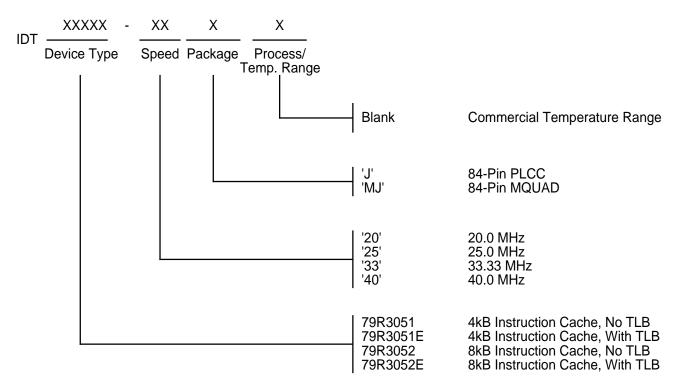


NOTES:

- 1. All dimensions are in inches, unless otherwise noted.
- All difficults are in inches, diffess otherwise
 BSC—Basic lead Spacing between Centers.
 D & E do not include mold flash or protutions.
- 4. Formed leads shall be planar with respect to one another and within .004" at the seating plane.
- 5. ND & NE represent the number of leads in the D & E directions respectively.
 6. D1 & E1 should be measured from the bottom of the package.
- 7. MQUAD is pin & form compatible with PLCC.

DWG #	J84-1		MJ8	34-1	
# of Leads	8	4	84		
Symbol	Min.	Max.	Min.	Max.	
Α	165	.180	165	.180	
A1	.095	.115	.094	.114	
В	.026	.032	.026	.032	
b1	.013	.021	.013	.021	
С	.020	.040	.020	.040	
C1	.008	.012	.008	.012	
D	1.185	1.195	1.185	1.195	
D1	1.150	1.156	1.140	1.150	
D2/E2	1.090	1.130	1.090	1.130	
D3/E3	1.000	REF	1.000	REF	
E	1.185	1.195	1.185	1.195	
E1	1.150	1.156	1.140	1.150	
е	.050	BSC	.050	BSC	
ND/NE	2	21	2	1	

ORDERING INFORMATION



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VALID COMBINATIONS

IDT	79R3051 - 20, 25 79R3051E - 20, 25 79R3052 - 20, 25 79R3052E - 20, 25	J Packages Only J Packages Only J Packages Only J Packages Only
	79R3051 - 33, 40 79R3051E - 33, 40 79R3052 - 33, 40 79R3052E - 33, 40	MJ Packages Only MJ Packages Only MJ Packages Only MJ Packages Only